

L Number	Hits	Search Text	DB	Time stamp
4	1282	((118/712) or (118/713)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/02 00:46
47	13	"6016562"	USPAT	2003/06/02 01:15
48	1	("6031607").PN.	USPAT	2003/06/02 01:16
448	7	356/\$.ccls. and (adjustable near3 intens\$4) and semiconductor and thickness ✓	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/02 01:42
449	25	356/\$.ccls. and (adjustable near3 illuminat\$4) and semiconductor and thickness	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/02 01:37
450	73	356/\$.ccls. and (variable near3 intens\$4) and semiconductor and thickness	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/02 01:42
-	915231	@pd>20020514	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 02:51
-	0	118/\$.ccls. and ((illuminat\$ near5 visual) same (semiconductor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 02:53
-	90	@pd>20020514 and (118/50.ccls. or 118/52.ccls. or 118/50.1.ccls. or 118/56.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 02:54
-	150	@pd>20020514 and (118/320.ccls. or 118/326.ccls. or 118/712.ccls. or 118/713.ccls. or 118/501.ccls. or 118/500.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 04:08
-	307	@pd>20020514 and (222/113.ccls. or 362/231.ccls. or 355/53.ccls. or 355/70.ccls. or 396/611.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 11:24
-	157	@pd>20020514 and (156/379.ccls. or 427/8.ccls. or 427/9.ccls. or 427/10.ccls. or 427/240.ccls. or 427/425.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 11:24
-	259	@pd>20020514 and (362/145.ccls. or 362/147.ccls. or 362/149.ccls. or 362/154.ccls. or 362/155.ccls. or 362/800.ccls. or 362/803.ccls. or 362/458.ccls. or 362/253.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 11:25
-	14	118/\$.ccls. and ((visual near3 inspection) same (chuck or holder or table))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 02:54

-	9	118/\$.ccls. and ((visual near3 inspection) same (semiconductor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 02:54
-	80	118/\$.ccls. and ((illuminat\$) same (semiconductor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 02:54
-	169	118/\$.ccls. and ((illuminat\$) same (chamber))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 02:54
-	558	(427/\$.ccls. or 118/\$.ccls.) and (LED or "light emitting diode" or "light emitting diodes") and controller	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 02:55
-	1	"5843527".PN.	USPAT	2002/12/16 03:05
-	171	(427/\$.ccls. or 118/\$.ccls.) and (LED or "light emitting diode" or "light emitting diodes") and (controller same (input or output))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 03:20
-	1	6122042.pn.	USPAT	2002/12/16 03:06
-	1	6122042.pn. and (coat or coating)	USPAT	2002/12/16 03:07
-	0	(427/\$.ccls. or 118/\$.ccls.) and (*diode*) and (thickness) and (photoresist)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 03:21
-	0	(427/\$.ccls. or 118/\$.ccls.) and (*diode*) and (thickness)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 03:21
-	303	(427/\$.ccls. or 118/\$.ccls.) and (photodiode) and (thickness)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 03:31
-	44	(427/\$.ccls. or 118/\$.ccls.) and (photodiode) and (thickness) and photoresist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 03:21
-	31	(118/\$.ccls.) and (photodiode) and (thickness) and controller	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 03:37
-	7	"5985357"	USPAT	2002/12/16 04:16
-	68	process and chamber and anti-reflective and 118/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 11:27
-	4620	(118/320.ccls. or 118/326.ccls. or 118/712.ccls. or 118/713.ccls. or 118/501.ccls. or 118/500.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 04:08
-	1	4713140.pn.	USPAT	2002/12/16 10:22

-	1	4696209.pn.	USPAT	2002/12/16 11:19
-	1	4227347.pn.	USPAT	2002/12/16 11:19
-	3036	(222/113.ccls. or 362/231.ccls. or 355/53.ccls. or 355/70.ccls. or 396/611.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 11:24
-	3255	156/379.ccls. or 427/8.ccls. or 427/9.ccls. or 427/10.ccls. or 427/240.ccls. or 427/425.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 11:25
-	3803	(362/145.ccls. or 362/147.ccls. or 362/149.ccls. or 362/154.ccls. or 362/155.ccls. or 362/800.ccls. or 362/803.ccls. or 362/458.ccls. or 362/253.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 11:54
-	366814	process and chamber and non-reflective and 118/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 11:42
-	10	process and chamber and non-reflective and 118/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 11:43
-	4	process and chamber and nonreflective and 118/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/16 11:44
-	160	118/677	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/02 01:14
-	1214	438/16	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/31 22:19
-	114	438/16 and reflectivity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/01 22:57
-	16	438/16 and (illumination near3 intensity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/01 23:38
-	1	(118/713.ccls.) and (illumination near3 intensity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/01 23:37
-	4	(118/712.ccls.) and (illumination near3 intensity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/01 23:37

-	20	438/16 and (illuminat\$4 near3 intens\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/01 23:48
-	1910	356/\$.ccls. and (illuminat\$4 near3 intens\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/01 23:48
-	559	356/\$.ccls. and (illuminat\$4 near3 intens\$4) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/01 23:50
-	281	356/\$.ccls. and (illuminat\$4 near3 intens\$4) and semiconductor and thickness	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/02 01:34